

## **Preliminary**

# **GRF5020**

30.5 dBm Power-LNA™ Tuning Range: 0.1 – 3.8 GHz



### **Features**

Reference: 8.0V/95mA/2.5GHz

Gain: 18.0 dBNF: 0.85 dB

OP1dB: 29.0 dBmOIP3: 43.0 dBm

Reference: 5.0V/65mA/2.5GHz

Gain: 17.3 dBNF: 0.80 dB

OP1dB: 24.5 dBmOIP3: 37.2 dBm

Flexible Bias Voltage and Current

Process: GaAs pHEMT

### Applications

Multi-stage LNA

 Linear Driver Amplifier for High PAR Waveforms

Distributed Antenna Systems

Microwave Backhaul

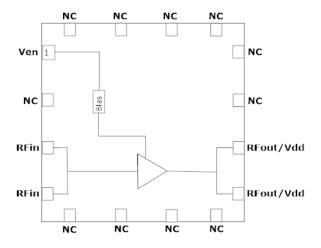
Revision Date: 10/01/19

### **Product Description**

GRF5020 is a high linearity PA with ultra-low noise figure (NF). The primary tune for this device covers 1.7 to 2.7 GHz and it achieves outstanding P1dB, IP3 and NF over the band. The device can be tuned to deliver outstanding performance over 0.1 GHz. to 6.0 GHz with fractional bandwidths >30%. With a 10.0 Volt supply, the device can deliver broadband OP1dB values >30.0 dBm.

In addition to use as a PA or linear driver, GRF5020 is well suited to demanding first, second or third stage LNA applications requiring high linearity, ruggedness and low NF.

Consult with the GRF applications engineering team for custom tuning/evaluation board data and device sparameters.



3.0 x 3.0 mm QFN-16



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## **Absolute Ratings:**

Parameter	Symbol	Min.	Max.	Unit
Drain Voltage	V <sub>DD</sub>		12.0	V
Transient Average RF Input Power CW: (Load VSWR < 2:1; Duration: <1 hour)	PIN MAX		22.0	dBm
Average RF Output Power: (Load VSWR < 2:1; V <sub>D</sub> : > 8.0 volts; Duration: Continuous)	Роит мах		26.0	dBm
Average RF Output Power: (Load VSWR < 2:1; V <sub>D</sub> : <= 8.0 volts; Duration: Continuous)	Роит мах		NA	dBm
Operating Temperature (Package Heat Sink)	T <sub>AMB</sub>	-40	105	°C
Maximum Channel Temperature (MTTF > 10^6 Hours)	Тмах		170	°C
Maximum Dissipated Power	P <sub>DISS MAX</sub>		1.9	W
Electrostatic Discharge:				
Charged Device Model: (TBD)	CDM	1500		V
Human Body Model:	НВМ	250		V
Storage:				
Storage Temperature	T <sub>STG</sub>	-65	150	°C
Moisture Sensitivity Level	MSL		1	-



Caution! ESD Sensitive Device



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Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

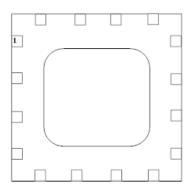
Note: For manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF5020 landing page: Manufacturing Note-MN-001 Product Tape and Reel, Solderability and Package Outline Specification.

Link to manufacturing note



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### Pin Out (Top View)



## Pin Assignments:

Pin	Name	Description	Note
1	V <sub>ENABLE</sub>	Enable Voltage Input	Venable and series resistor set IDDQ. Venable < =0.2 volts disables device. On-die pull-down resistor will turn the part off if this node is allowed to float.
2	NC	No Connect or Ground	No internal connection to die
3	RF_In	RF Input	Pins 3-4 tied together on system board
4	RF_In	RF Input	Pins 3-4 tied together on system board
5	NC	No Connect or Ground	No internal connection to die
6	NC	No Connect or Ground	No internal connection to die
7	NC	No Connect or Ground	No internal connection to die
8	NC	No Connect or Ground	No internal connection to die
9	RF_Out/VDD	PA Output/Bias	Pins 9-10 tied together on system board. Supply Vdd here.
10	RF_Out/VDD	PA Output/Bias	Pins 9-10 tied together on system board. Supply Vdd here.
11	NC	No Connect or Ground	No internal connection to die
12	NC	No Connect or Ground	No internal connection to die
13	NC	No Connect or Ground	No internal connection to die
14	NC	No Connect or Ground	No internal connection to die
15	NC	No Connect or Ground	No internal connection to die
16	NC	No Connect or Ground	No internal connection to die
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.



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### **Nominal Operating Parameters:**

Parameter	Cyroob ol	Specification			Unit	Condition	
rafaffieter	Symbol	Min.	Тур.	Max.	Ullit	Condition	
Target Performance (1.7-3.8 GHz Tune)						Bias: 8.0 V and 95 mA unless otherwise noted. (+25C)	
Test Frequency	FTEST		2.5		GHz		
Gain	S(2,1)	16.0	17.5		dB		
Noise Figure (Evaluation Board)	NF		0.85	1.05	dB		
Output 1dB Compression Point	OP1dB	27.5	29.0		dBm		
Output Third Order Intercept Point	OIP3		43.0		dBm	Tones: 2499 and 2501 MHz at 8.0 dBm per tone	
Switching Rise Time	Trise		200		ns		
Switching Fall Time	TFALL		200		ns		
Quiescent Supply Current	IDDQ		95		mA		
Enable Current	<b>I</b> ENABLE		2.0		mA		
Disabled Mode						VDD: 8.0 volts; VENABLE: 0.0 volts	
Supply Current (Leakage)	I <sub>DD</sub>		300	600	uA		
Thermal Data							
Thermal Resistance: (IR Scan Method)	Θјс		43		°C/W		
Channel Temperature @ +85C Reference (package heat sink)	TCHANNEL		118 (See note)		°C	V <sub>DD</sub> : 8.0 volts; I <sub>DDQ</sub> : 95 mA P <sub>DISS</sub> : 0.76 W; No RF	

Note: MTTF >10<sup>6</sup> hours for Tchannel < =170 degrees C.

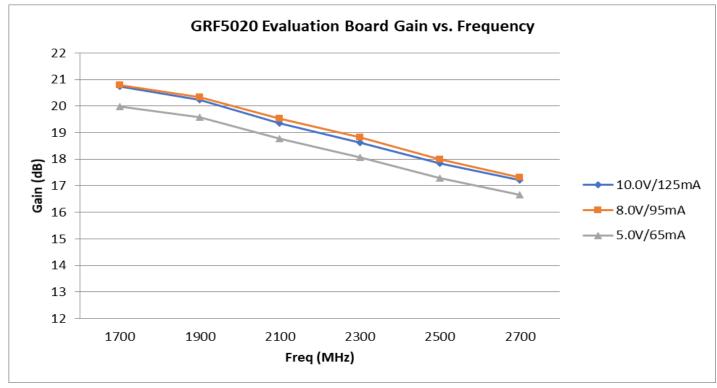


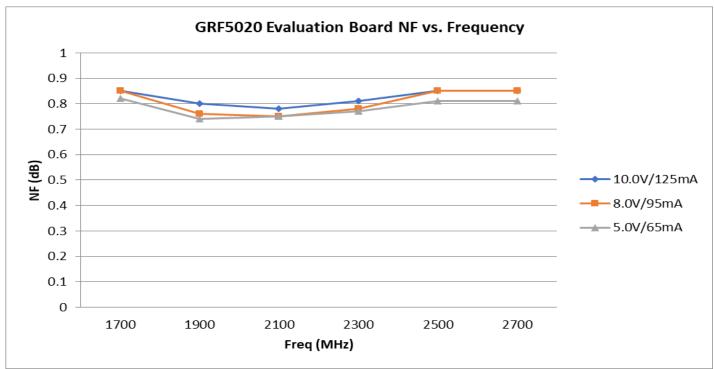
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# **GRF5020**

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### **GRF5020 Evaluation Board Data vs. Supply Voltage (1.7 to 2.7GHz Tune)**





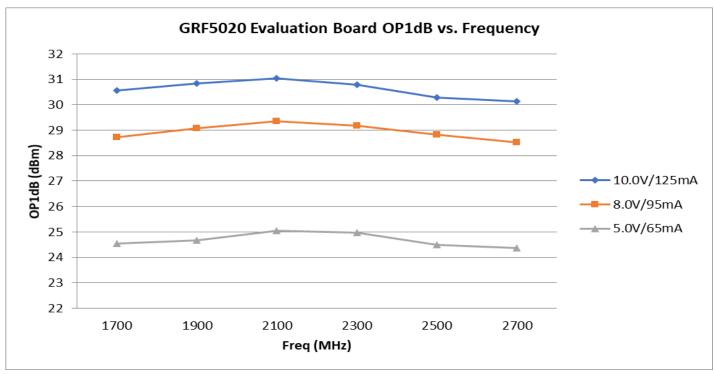


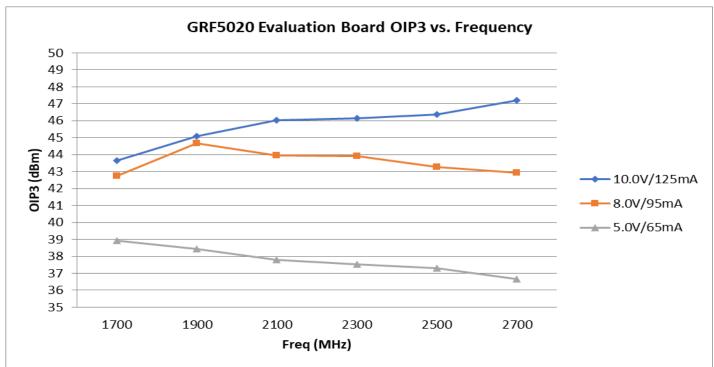
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## **GRF5020** Evaluation Board Data vs. Supply Voltage (1.7 to 2.7GHz Tune)





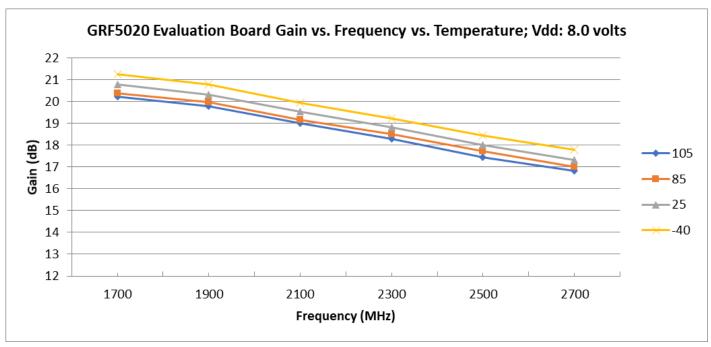


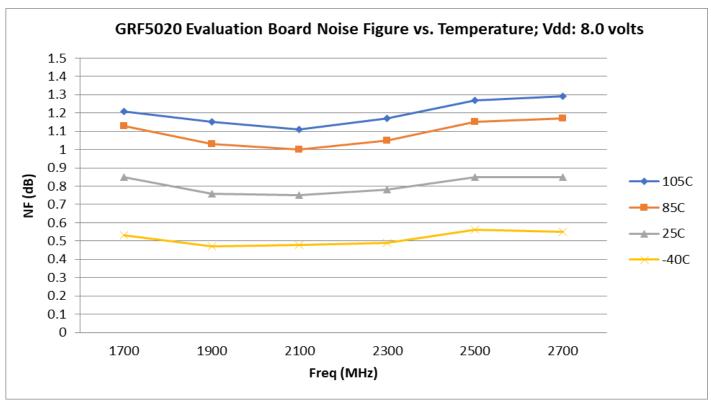
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GRF5020 Evaluation Board Data vs. Temperature; Bias: 8.0 volts (1.7 to 2.7GHz Tune)





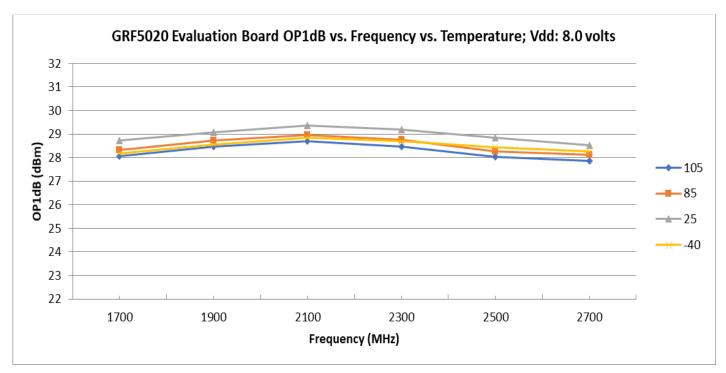


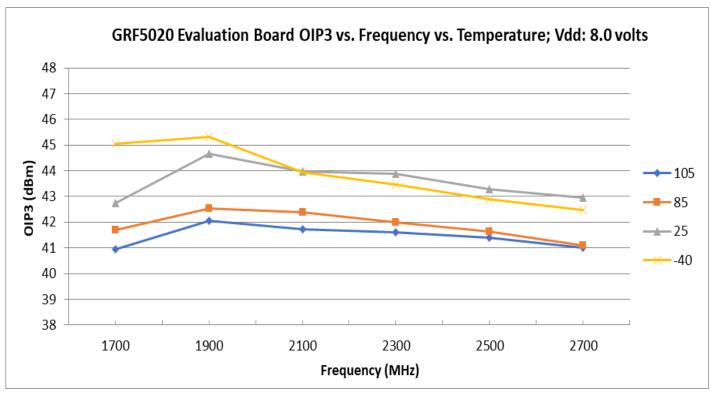
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30.5 dBm Power-LNA™ Tuning Range: 0.1 – 3.8 GHz

### **GRF5020** Evaluation Board Data vs. Temperature; Bias: 8.0 volts (1.7 to 2.7GHz Tune)



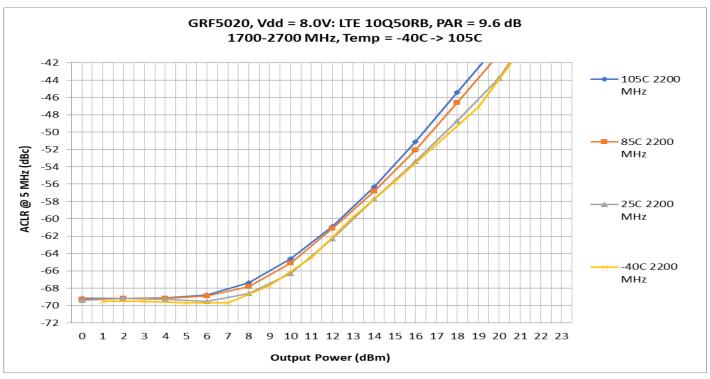


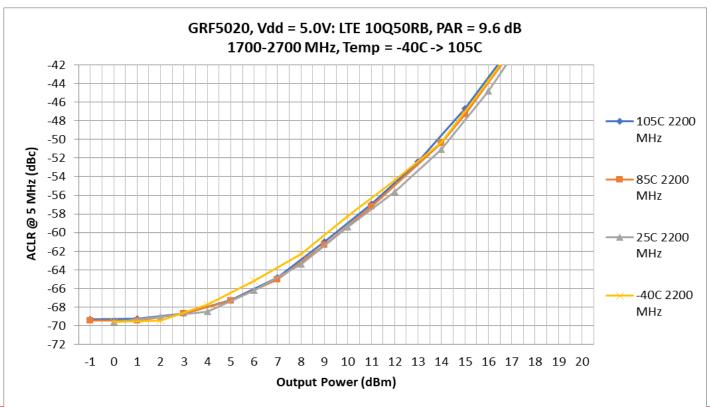


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30.5 dBm Power-LNA™ Tuning Range: 0.1 - 3.8 GHz

### **GRF5020 Evaluation Board Data vs. Temperature**; (1.7 to 2.7GHz Tune)



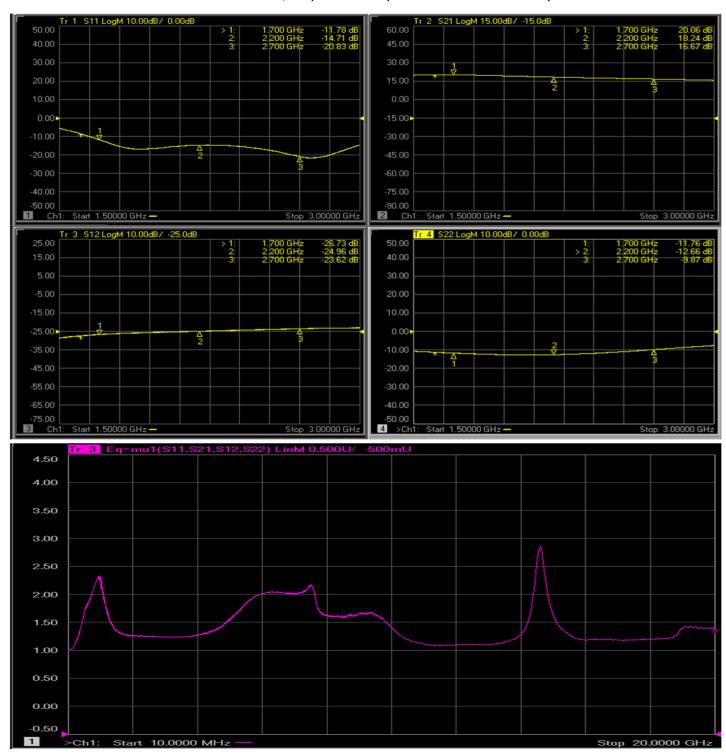


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### GRF5020 Evaluation Board S-Pars; 5V/95 mA: (1.7 to 2.7 GHz Tune)

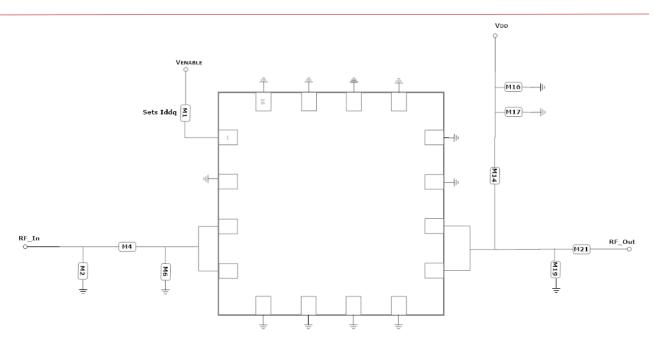


Note: Mu factor >= 1.0 implies unconditional stability.

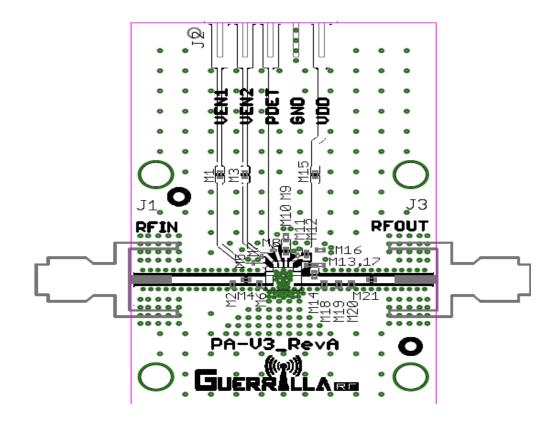


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**GRF5020 Application Schematic:** (1.7 to 2.7 GHz)



**GRF50XX Evaluation Board Assembly Drawing** 



# **GRF5020**

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## GRF5020 Evaluation Board BOM: (1.7—2.7GHz)

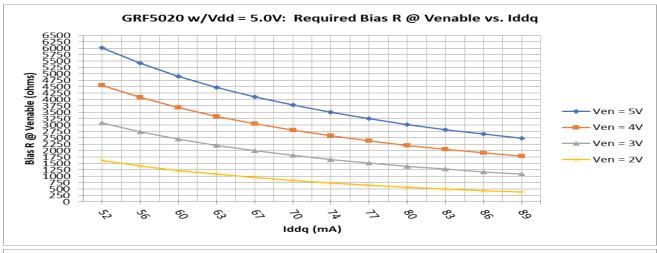
Component	Туре	Manufacturer	Family	Value	Package Size	Substitution
M1 (See curves)	Resistor	Various	5%	Sets Iddq	0402	ok
M2	Inductor: High Q	Coilcraft	НР	3.3 nH	0402	ok
M4	Capacitor: High Q	Murata	GJM	2.0 pF	0402	ok
M6	Capacitor: High Q	Murata	GJM	1.8 pF	0402	ok
M14	Inductor: High Q	Coilcraft	НР	15 nH	0402	ok
M16	Capacitor	Murata	GRM	0.1 uF	0402	ok
M17	Capacitor	Murata	GRM	100 pF	0402	ok
M19	DNP	_	_	_	_	_
M21	Capacitor	Murata	GJM	18 pF	0402	ok
Evaluation Board	PA-V3_RevA					

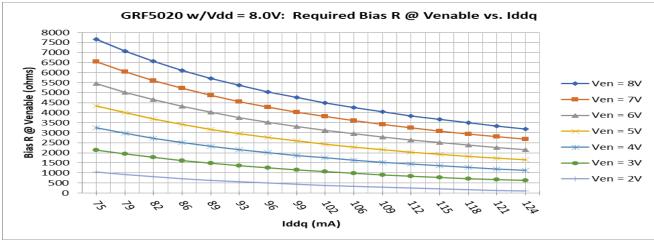


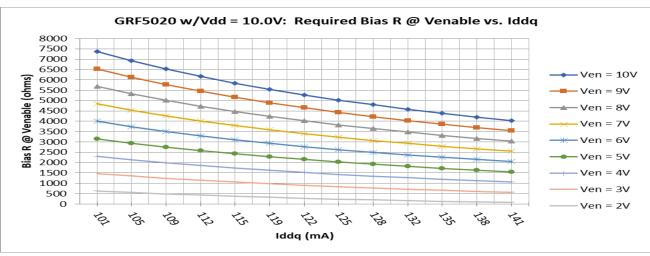
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### GRF5020 Bias Resistor (M1) Selection Curves:





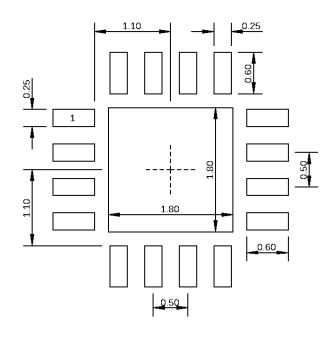


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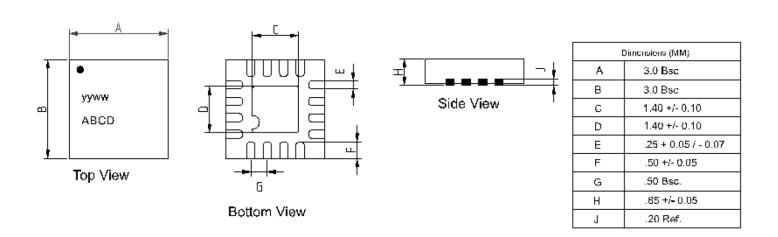
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Dimensions in millimeters

### 3.0 mm QFN-16 Suggested PCB Footprint (Top View)



3.0 mm QFN-16 Package Dimensions



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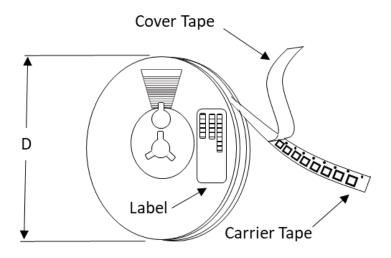
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### Tape and Reel Information:

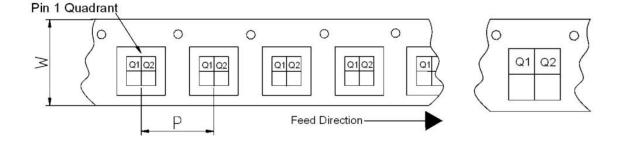
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Guerrilla RF's Tape and Reel specification complies with the Electronics Industries Association (EIA) standards for 'Embossed Carrier Tape of Surface Mount Components for Automatic Handling". Reference EIA-481. See the table on the following page for Tape and Reel specifications along with units per reel.

Devices are loaded with pins down into the carrier pocket with protective cover tape, wound into a plastic reel. Each reel will be packaged in a cardboard box. There will be product labels on the reel, the protective ESD bag and the outside surface of the box.



Tape and Reel Packaging with Reel Diameter Noted (D)



Carrier Tape Width (W), Pitch (P), Feed Direction and Pin 1 Quadrant Information



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### Tape and Reel Specification and Device Package Information Table

Package			Carrier Tape			Reel		
Туре	Dimensions (mm)	Leads	Weight (mg)	Width (W) (mm)	Pocket Pitch (P) (mm)	Pin 1 Quad- rant	Diameter (D) (inches)	Units per Reel
QFN	2.0 x 2.0 x 0.50	12	7	8	4	Q1	7	2500
QFN	3.0 x 3.0 x 0.85	16	24	12	8	Q1	7	1500
DFN	1.5 x 1.5 x 0.45	6	4	8	4	Q1	7	2500
DFN	2.0 x 2.0 x 0.75	8	12	8	4	Q1	7	2500
LFM	3.5 x 3.5 x 0.75	See note	TBD	12	8	Q2	7	1500
LFM	4.0 x 4.0 x 0.75	See note	TBD	12	8	Q2	7	1500

Note: Lead count may vary. Reference applicable product data sheet



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Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

Information in this datasheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

Revision Date: 10/01/19

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